



Low Voltage 1.15 V to 5.5 V, 8-Channel Bidirectional Logic Level Translator

ADG3300

FEATURES

Bidirectional level translation
Operates from 1.15 V to 5.5 V
Low quiescent current <1 μ A
No direction pin

APPLICATIONS

Low voltage ASIC level translation
Smart card readers
Cell phones and cell phone cradles
Portable communications devices
Telecommunications equipment
Network switches and routers
Storage systems (SAN/NAS)
Computing/server applications
GPS
Portable POS systems
Low cost serial interfaces

GENERAL DESCRIPTION

The ADG3300 is a bidirectional logic level translator that contains eight bidirectional channels. It can be used in multivoltage digital system applications such as data transfer between a low voltage DSP/controller and a higher voltage device. The internal architecture allows the device to perform bidirectional logic level translation without an additional signal to set the direction of the translation.

The voltage applied to V_{CCA} sets the logic levels on the A side of the device, while V_{CCY} sets the levels on the Y side. For proper operation, V_{CCA} must always be less than V_{CCY} . The V_{CCA} -compatible logic signals applied to the A side of the device appear as V_{CCY} -compatible levels on the Y side. Similarly, V_{CCY} -compatible logic levels applied to the Y side of the device appear as V_{CCA} -compatible logic levels on the A side.

The enable pin provides three-state operation of the Y side pins. When the enable pin (EN) is pulled low, the A1 to A8 pins are

FUNCTIONAL BLOCK DIAGRAM

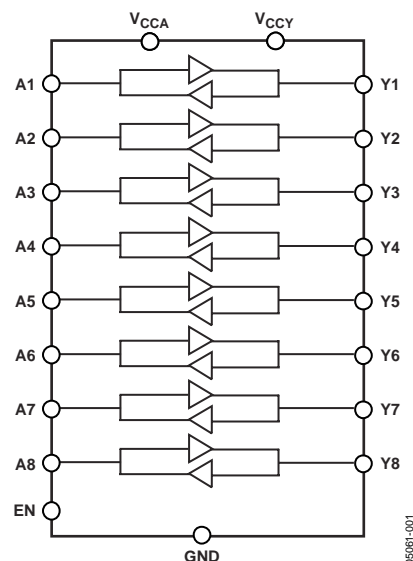


Figure 1.

internally pulled down by 6 k Ω resistors, while the Y terminals are in the high impedance state. The EN pin is referred to V_{CCA} supply voltage and driven high for normal operation.

The ADG3300 is available in a compact 20-lead TSSOP package, and it is guaranteed to operate over the 1.15 V to 5.5 V supply voltage range and extended -40°C to $+85^{\circ}\text{C}$ temperature range.

PRODUCT HIGHLIGHTS

1. Bidirectional level translation.
2. Fully guaranteed over the 1.15 V to 5.5 V supply range.
3. No direction pin.
4. 20-lead TSSOP package.

Rev. 0

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REVISION HISTORY

4/05—Revision 0: Initial Version

SPECIFICATIONS¹

$V_{CCY} = 1.65\text{ V to }5.5\text{ V}$, $V_{CCA} = 1.15\text{ V to }V_{CCY}$, $GND = 0\text{ V}$. All specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ ²	Max	Unit
LOGIC INPUTS/OUTPUTS						
A Side						
Input High Voltage ³	V_{IHA}	$V_{CCA} = 1.15\text{ V}$	$V_{CCA} - 0.3$			V
	V_{IHA}	$V_{CCA} = 1.2\text{ V to }5.5\text{ V}$	$V_{CCA} - 0.4$			V
Input Low Voltage ³	V_{ILA}				0.4	V
Output High Voltage	V_{OHA}	$V_Y = V_{CCY}$, $I_{OH} = 20\text{ }\mu\text{A}$, Figure 27	$V_{CCA} - 0.4$			V
Output Low Voltage	V_{OLA}	$V_Y = 0\text{ V}$, $I_{OL} = 20\text{ }\mu\text{A}$, Figure 27			0.4	V
Three-State Pull-Down Resistance	$R_{A,HIZ}$	$EN = 0$	4.2	6	8.4	k Ω
Y Side						
Input Low Voltage ³	V_{IHY}		$V_{CCY} - 0.4$			V
Input High Voltage ³	V_{ILY}				0.4	V
Output High Voltage	V_{OHY}	$V_A = V_{CCA}$, $I_{OH} = 20\text{ }\mu\text{A}$, Figure 28	$V_{CCY} - 0.4$			V
Output Low Voltage	V_{OLY}	$V_A = 0\text{ V}$, $I_{OL} = 20\text{ }\mu\text{A}$, Figure 28			0.4	V
Capacitance ³	C_Y	$f = 1\text{ MHz}$, $EN = 0$, Figure 31		6		pF
Leakage Current	$I_{LY, HIZ}$	$V_Y = 0\text{ V}/V_{CCY}$, $EN = 0$, Figure 29			± 1	μA
Enable (EN)						
Input High Voltage ³	V_{IHEN}	$V_{CCA} = 1.15\text{ V}$	$V_{CCA} - 0.3$			V
	V_{IHEN}	$V_{CCA} = 1.2\text{ V to }5.5\text{ V}$	$V_{CCA} - 0.4$			V
Input Low Voltage ³	V_{ILEN}				0.4	V
Leakage Current	I_{LEN}	$V_{EN} = 0\text{ V}/V_{CCA}$, $V_A = 0\text{ V}$, Figure 30			± 1	μA
Capacitance ³	C_{EN}			3		pF
Enable Time ³	t_{EN}	$R_S = R_T = 50\text{ }\Omega$, $V_A = 0\text{ V}/V_{CCA}$ (A Y), Figure 32		1	1.8	μs
SWITCHING CHARACTERISTICS³						
$3.3\text{ V} \pm 0.3\text{ V} \leq V_{CCA} \leq V_{CCY}$, $V_{CCY} = 5\text{ V} \pm 0.5\text{ V}$						
A Y Level Translation						
Propagation Delay	$t_{P, A-Y}$	$R_S = R_T = 50\text{ }\Omega$, $C_L = 50\text{ pF}$, Figure 33		6	10	ns
Rise Time	$t_{R, A-Y}$			2	3.5	ns
Fall Time	$t_{F, A-Y}$			2	3.5	ns
Maximum Data Rate	$D_{MAX, A-Y}$		50			Mbps
Channel-to-Channel Skew	$t_{SKEW, A-Y}$			2	4	ns
Part-to-Part Skew	$t_{PPSKEW, A-Y}$				3	ns
Y A Level Translation						
Propagation Delay	$t_{P, Y-A}$	$R_S = R_T = 50\text{ }\Omega$, $C_L = 15\text{ pF}$, Figure 34		4	7	ns
Rise Time	$t_{R, Y-A}$			1	3	ns
Fall Time	$t_{F, Y-A}$			3	7	ns
Maximum Data Rate	$D_{MAX, Y-A}$		50			Mbps
Channel-to-Channel Skew	$t_{SKEW, Y-A}$			2	3.5	ns
Part-to-Part Skew	$t_{PPSKEW, Y-A}$				2	ns
$1.8\text{ V} \pm 0.15\text{ V} \leq V_{CCA} \leq V_{CCY}$, $V_{CCY} = 3.3\text{ V} \pm 0.3\text{ V}$						
A Y Translation						
Propagation Delay	$t_{P, A-Y}$	$R_S = R_T = 50\text{ }\Omega$, $C_L = 50\text{ pF}$, Figure 33		8	11	ns
Rise Time	$t_{R, A-Y}$			2	5	ns
Fall Time	$t_{F, A-Y}$			2	5	ns
Maximum Data Rate	$D_{MAX, A-Y}$		50			Mbps
Channel-to-Channel Skew	$t_{SKEW, A-Y}$			2	4	ns
Part-to-Part Skew	$t_{PPSKEW, A-Y}$				4	ns

ADG3300

Parameter	Symbol	Conditions	Min	Typ ²	Max	Unit
Y A Translation		$R_S = R_T = 50\ \Omega$, $C_L = 15\ \text{pF}$, Figure 34				
Propagation Delay	$t_{P, Y-A}$			5	8	ns
Rise Time	$t_{R, Y-A}$			2	3.5	ns
Fall Time	$t_{F, Y-A}$			2	3.5	ns
Maximum Data Rate	$D_{MAX, Y-A}$		50			Mbps
Channel-to-Channel Skew	$t_{SKEW, Y-A}$			2	3	ns
Part-to-Part Skew	$t_{PPSKEW, Y-A}$				3	ns
1.15 V to 1.3 V $\leq V_{CCA} \leq V_{CCY}$, $V_{CCY} = 3.3\ \text{V} \pm 0.3\ \text{V}$						
A Y Translation		$R_S = R_T = 50\ \Omega$, $C_L = 50\ \text{pF}$, Figure 33				
Propagation Delay	$t_{P, A-Y}$			9	18	ns
Rise Time	$t_{R, A-Y}$			3	5	ns
Fall Time	$t_{F, A-Y}$			2	5	ns
Maximum Data Rate	$D_{MAX, A-Y}$		40			Mbps
Channel-to-Channel Skew	$t_{SKEW, A-Y}$			2	5	ns
Part-to-Part Skew	$t_{PPSKEW, A-Y}$				10	ns
Y A Translation		$R_S = R_T = 50\ \Omega$, $C_L = 15\ \text{pF}$, Figure 34				
Propagation Delay	$t_{P, Y-A}$			5	9	ns
Rise Time	$t_{R, Y-A}$			2	4	ns
Fall Time	$t_{F, Y-A}$			2	4	ns
Maximum Data Rate	$D_{MAX, Y-A}$		40			Mbps
Channel-to-Channel Skew	$t_{SKEW, Y-A}$			2	4	ns
Part-to-Part Skew	$t_{PPSKEW, Y-A}$				4	ns
1.15 V to 1.3 V $\leq V_{CCA} \leq V_{CCY}$, $V_{CCY} = 1.8\ \text{V} \pm 0.3\ \text{V}$						
A Y Translation		$R_S = R_T = 50\ \Omega$, $C_L = 50\ \text{pF}$, Figure 33				
Propagation Delay	$t_{P, A-Y}$			12	25	ns
Rise Time	$t_{R, A-Y}$			7	12	ns
Fall Time	$t_{F, A-Y}$			3	5	ns
Maximum Data Rate	$D_{MAX, A-Y}$		25			Mbps
Channel-to-Channel Skew	$t_{SKEW, A-Y}$			2	5	ns
Part-to-Part Skew	$t_{PPSKEW, A-Y}$				15	ns
Y A Translation		$R_S = R_T = 50\ \Omega$, $C_L = 15\ \text{pF}$, Figure 34				
Propagation Delay	$t_{P, Y-A}$			14	35	ns
Rise Time	$t_{R, Y-A}$			5	16	ns
Fall Time	$t_{F, Y-A}$			2.5	6.5	ns
Maximum Data Rate	$D_{MAX, Y-A}$		25			Mbps
Channel-to-Channel Skew	$t_{SKEW, Y-A}$			3	6.5	ns
Part-to-Part Skew	$t_{PPSKEW, Y-A}$				23.5	ns
2.5 V $\pm 0.2\ \text{V} \leq V_{CCA} \leq V_{CCY}$, $V_{CCY} = 3.3\ \text{V} \pm 0.3\ \text{V}$						
A Y Translation		$R_S = R_T = 50\ \Omega$, $C_L = 50\ \text{pF}$, Figure 33				
Propagation Delay	$t_{P, A-Y}$			7	10	ns
Rise Time	$t_{R, A-Y}$			2.5	4	ns
Fall Time	$t_{F, A-Y}$			2	5	ns
Maximum Data Rate	$D_{MAX, A-Y}$		60			Mbps
Channel-to-Channel Skew	$t_{SKEW, A-Y}$			1.5	2	ns
Part-to-Part Skew	$t_{PPSKEW, A-Y}$				4	ns
Y A Translation		$R_S = R_T = 50\ \Omega$, $C_L = 15\ \text{pF}$, Figure 34				
Propagation Delay	$t_{P, Y-A}$			5	8	ns
Rise Time	$t_{R, Y-A}$			1	4	ns
Fall Time	$t_{F, Y-A}$			3	5	ns
Maximum Data Rate	$D_{MAX, Y-A}$		60			Mbps
Channel-to-Channel Skew	$t_{SKEW, Y-A}$			2	3	ns
Part-to-Part Skew	$t_{PPSKEW, Y-A}$				3	ns

Parameter	Symbol	Conditions	Min	Typ ²	Max	Unit
POWER REQUIREMENTS						
Power Supply Voltages	V_{CCA}	$V_{CCA} \leq V_{CCY}$	1.15		5.5	V
	V_{CCY}		1.65		5.5	V
Quiescent Power Supply Current	I_{CCA}	$V_A = 0 \text{ V}/V_{CCA}, V_Y = 0 \text{ V}/V_{CCY},$ $V_{CCA} = V_{CCY} = 5.5 \text{ V}, EN = 1$		0.17	5	μA
	I_{CCY}	$V_A = 0 \text{ V}/V_{CCA}, V_Y = 0 \text{ V}/V_{CCY},$ $V_{CCA} = V_{CCY} = 5.5 \text{ V}, EN = 1$		0.27	5	μA
Three-State Mode Power Supply Current	I_{HIZA}	$V_{CCA} = V_{CCY} = 5.5 \text{ V}, EN = 0$		0.1	5	μA
	I_{HIZY}	$V_{CCA} = V_{CCY} = 5.5 \text{ V}, EN = 0$		0.1	5	μA

¹ Temperature range is as follows: B version: -40°C to $+85^{\circ}\text{C}$.

² All typical values are at $T_A = 25^{\circ}\text{C}$, unless otherwise noted.

³ Guaranteed by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

Parameter	Rating
V_{CCA} to GND	$-0.3\text{ V to }+7\text{ V}$
V_{CCY} to GND	V_{CCA} to $+7\text{ V}$
Digital Inputs (A)	$-0.3\text{ V to } (V_{CCA} + 0.3\text{ V})$
Digital Inputs (Y)	$-0.3\text{ V to } (V_{CCY} + 0.3\text{ V})$
EN to GND	$-0.3\text{ V to }+7\text{ V}$
Operating Temperature Range	
Industrial (B Version)	$-40^\circ\text{C to }+85^\circ\text{C}$
Storage Temperature Range	$-65^\circ\text{C to }+150^\circ\text{C}$
Junction Temperature	150°C
θ_{JA} Thermal Impedance (4-Layer Board)	
20-Lead TSSOP	78°C/W
Lead Temperature, Soldering (10 sec)	300°C
IR Reflow, Peak Temperature (<20 sec)	260°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

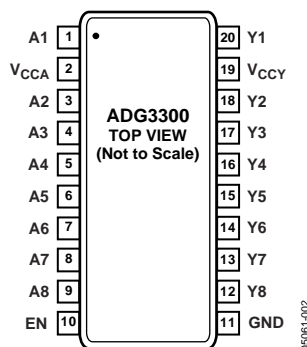


Figure 2. Pin Configuration

Table 3. Pin Function Descriptions

Pin. No.	Mnemonic	Description
1	A1	Input/Output A1. Referenced to V_{CCA} .
2	V_{CCA}	Power Supply Voltage Input for the A1 to A8 I/O pins ($1.15\text{ V} \leq V_{CCA} < V_{CCY}$).
3	A2	Input/Output A2. Referenced to V_{CCA} .
4	A3	Input/Output A3. Referenced to V_{CCA} .
5	A4	Input/Output A4. Referenced to V_{CCA} .
6	A5	Input/Output A5. Referenced to V_{CCA} .
7	A6	Input/Output A6. Referenced to V_{CCA} .
8	A7	Input/Output A7. Referenced to V_{CCA} .
9	A8	Input/Output A8. Referenced to V_{CCA} .
10	EN	Active High Enable Input.
11	GND	Ground.
12	Y8	Input/Output Y8. Referenced to V_{CCY} .
13	Y7	Input/Output Y7. Referenced to V_{CCY} .
14	Y6	Input/Output Y6. Referenced to V_{CCY} .
15	Y5	Input/Output Y5. Referenced to V_{CCY} .
16	Y4	Input/Output Y4. Referenced to V_{CCY} .
17	Y3	Input/Output Y3. Referenced to V_{CCY} .
18	Y2	Input/Output Y2. Referenced to V_{CCY} .
19	V_{CCY}	Power Supply Voltage Input for the Y1 to Y8 I/O pins ($1.65\text{ V} \leq V_{CCY} \leq 5.5\text{ V}$).
20	Y1	Input/Output Y1. Referenced to V_{CCY} .

TYPICAL PERFORMANCE CHARACTERISTICS

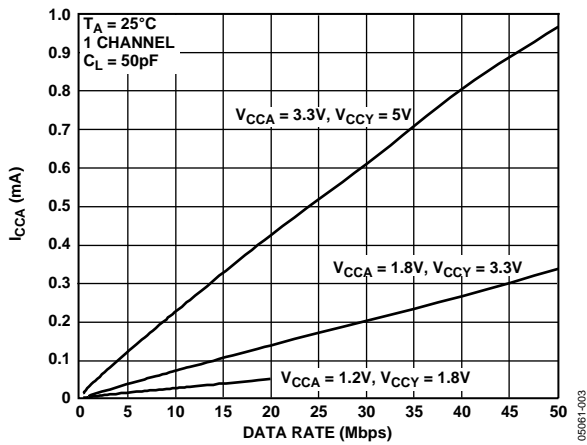


Figure 3. I_{CCA} vs. Data Rate (A Y Level Translation)

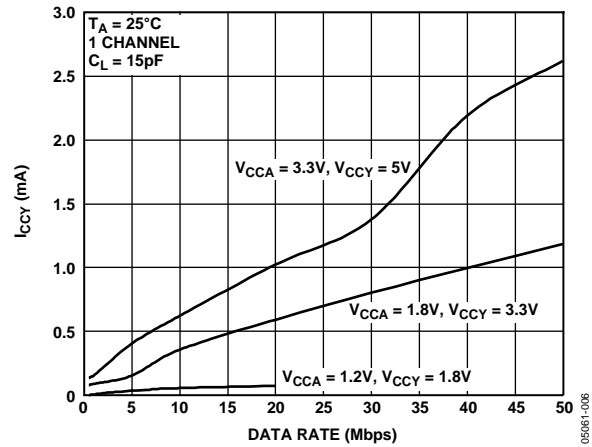


Figure 6. I_{CCY} vs. Data Rate (Y A Level Translation)

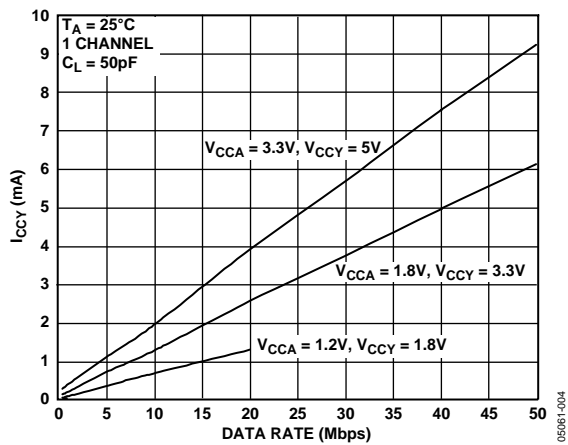


Figure 4. I_{CCY} vs. Data Rate (A Y Level Translation)

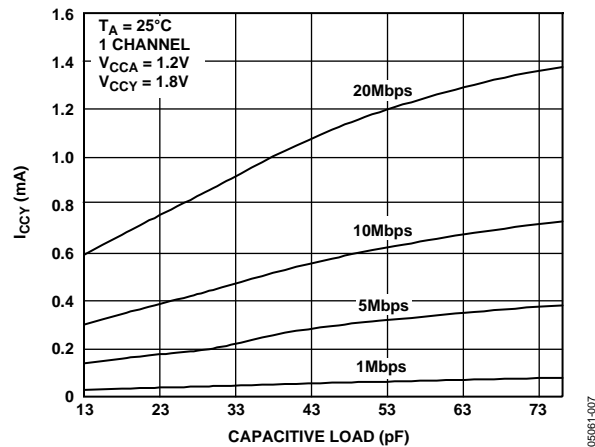


Figure 7. I_{CCY} vs. Capacitive Load at Pin Y for A Y (1.2 V 1.8 V) Level Translation

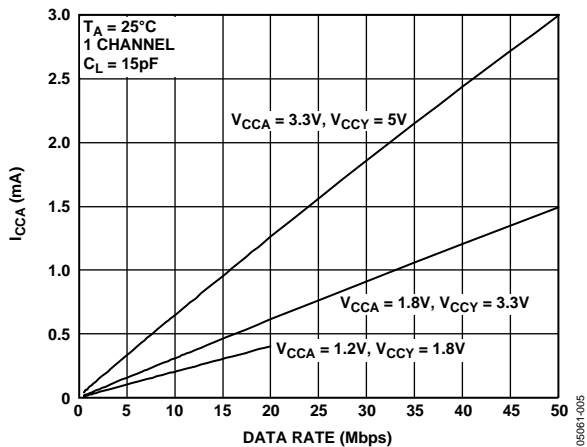


Figure 5. I_{CCA} vs. Data Rate (Y A Level Translation)

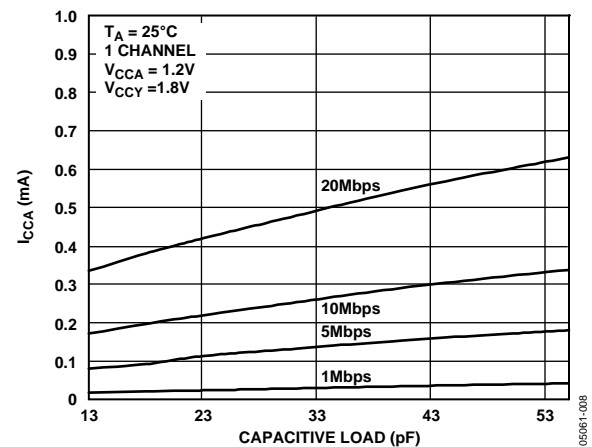


Figure 8. I_{CCA} vs. Capacitive Load at Pin A for Y A (1.8 V 1.2 V) Level Translation

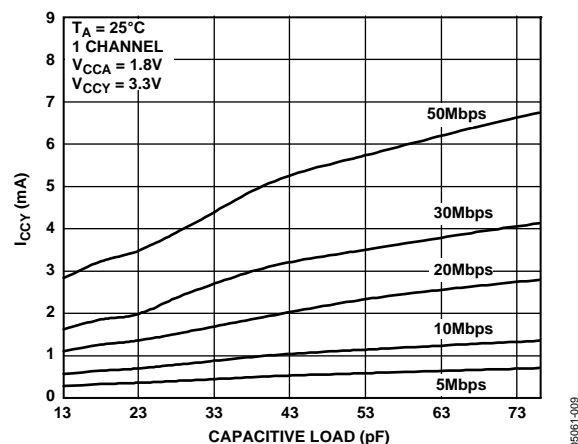


Figure 9. I_{CCY} vs. Capacitive Load at Pin Y for A Y (1.8 V 3.3 V) Level Translation

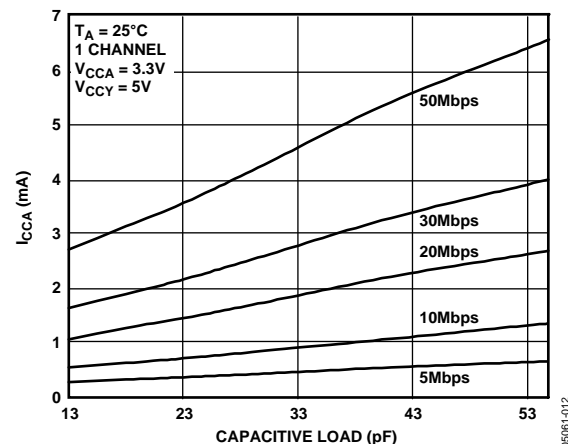


Figure 12. I_{CCA} vs. Capacitive Load at Pin A for Y A (5 V 3.3 V) Level Translation

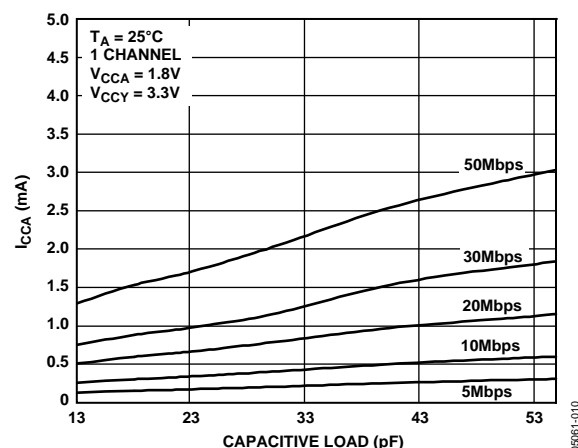


Figure 10. I_{CCA} vs. Capacitive Load at Pin A for Y A (3.3 V 1.8 V) Level Translation

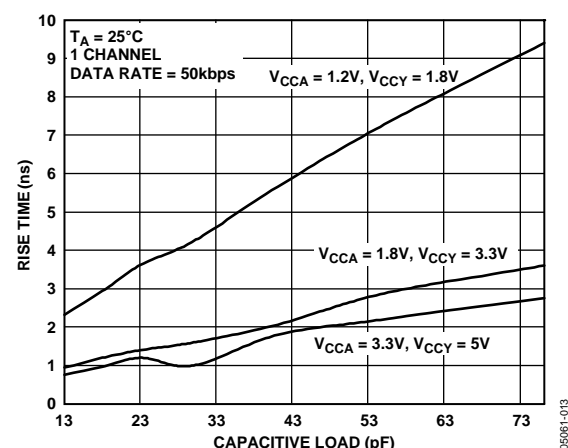


Figure 13. Rise Time vs. Capacitive Load at Pin Y (A Y Level Translation)

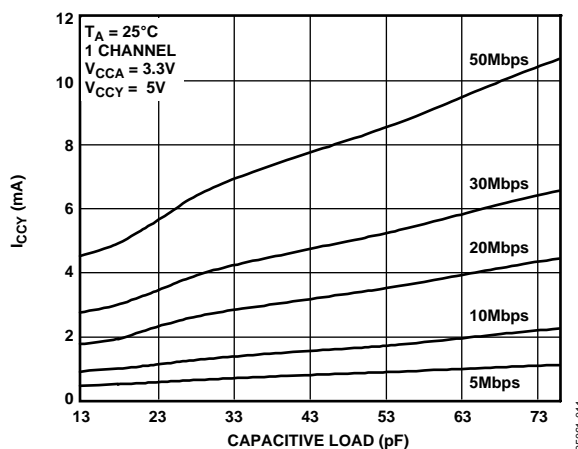


Figure 11. I_{CCY} vs. Capacitive Load at Pin Y for A Y (3.3 V 5 V) Level Translation

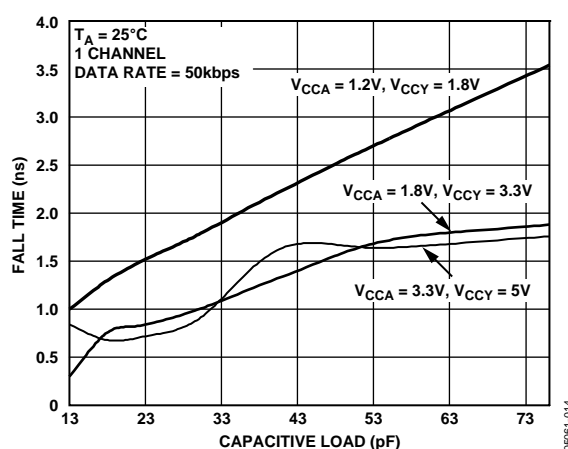


Figure 14. Fall Time vs. Capacitive Load at Pin Y (A Y Level Translation)

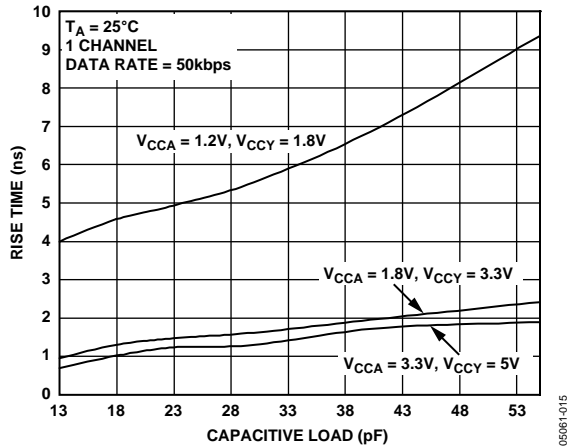


Figure 15. Rise Time vs. Capacitive Load at Pin A (Y A Level Translation)

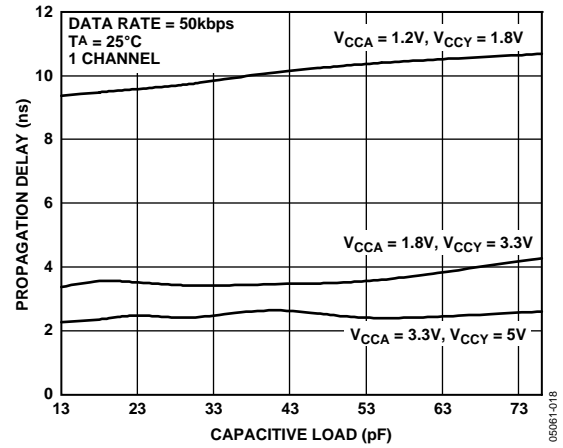


Figure 18. Propagation Delay (t_{PHL}) vs. Capacitive Load at Pin Y (Y A Level Translation)

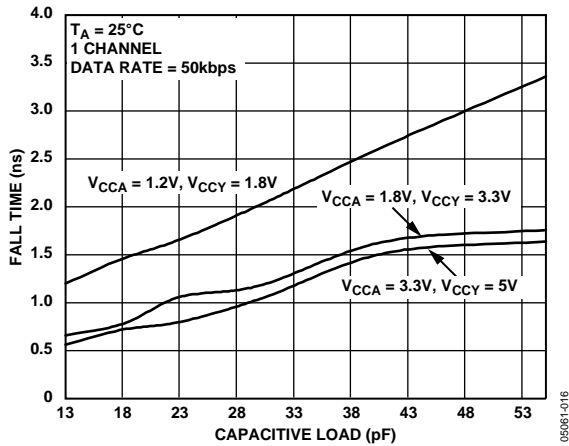


Figure 16. Fall Time vs. Capacitive Load at Pin A (Y A Level Translation)

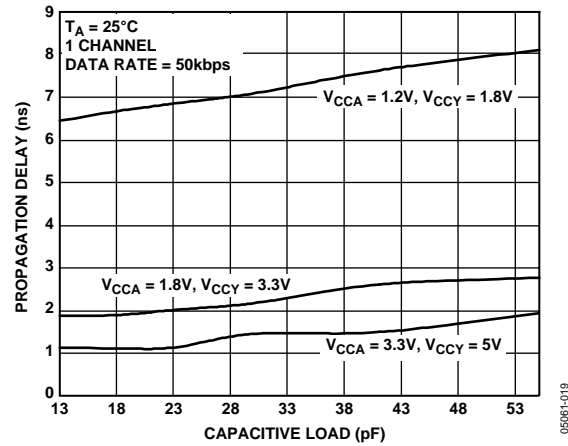


Figure 19. Propagation Delay (t_{PLH}) vs. Capacitive Load at Pin A (Y A Level Translation)

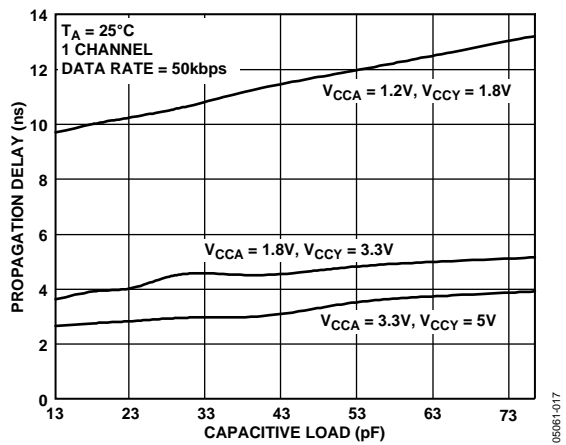


Figure 17. Propagation Delay (t_{PLH}) vs. Capacitive Load at Pin Y (A Y Level Translation)

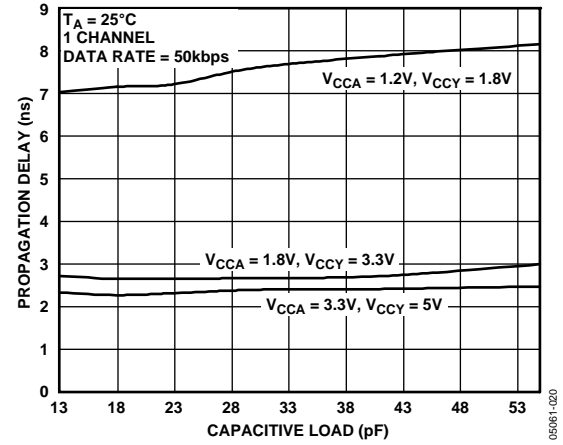


Figure 20. Propagation Delay (t_{PHL}) vs. Capacitive Load at Pin A (Y A Level Translation)

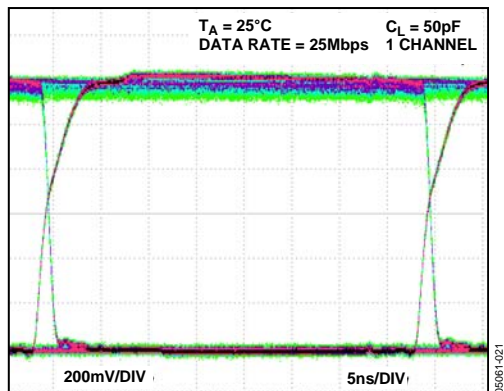


Figure 21. Eye Diagram at Y Output (1.2 V to 1.8 V Level Translation, 25 Mbps)

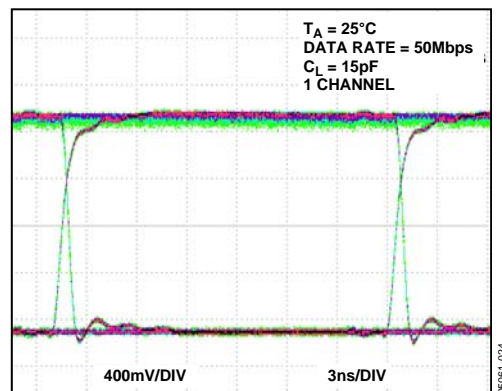


Figure 24. Eye Diagram at A Output (3.3 V to 1.8 V Level Translation, 50 Mbps)

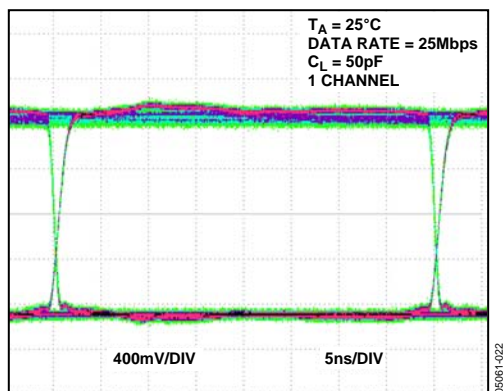


Figure 22. Eye Diagram at A Output (1.8 V to 1.2 V Level Translation, 25 Mbps)

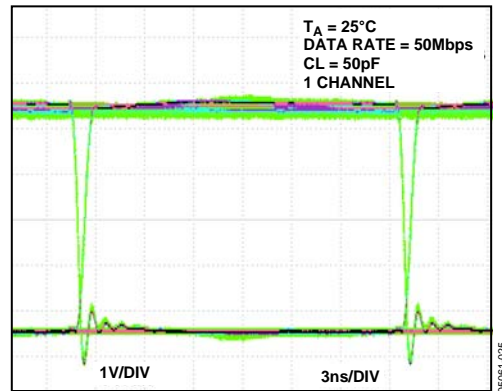


Figure 25. Eye Diagram at Y Output (3.3 V to 5 V Level Translation, 50 Mbps)

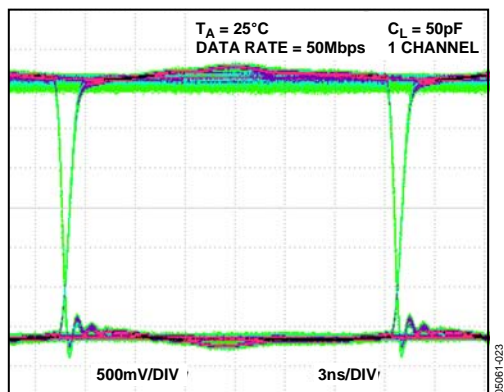


Figure 23. Eye Diagram at Y Output (1.8 V to 3.3 V Level Translation, 50 Mbps)

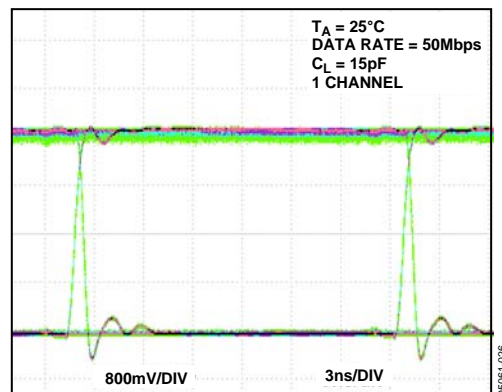


Figure 26. Eye Diagram at A Output (5 V to 3.3 V Level Translation, 50 Mbps)

TEST CIRCUITS

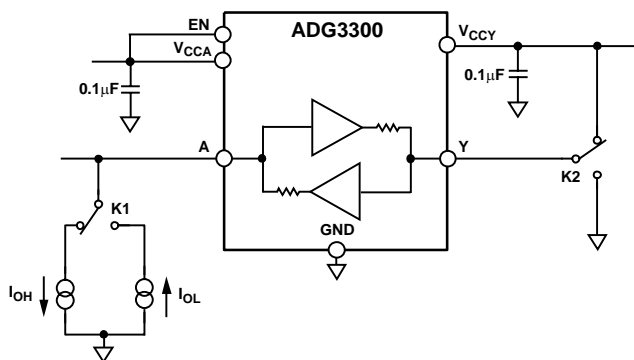


Figure 27. V_{OH}/V_{OL} Voltages at Pin A

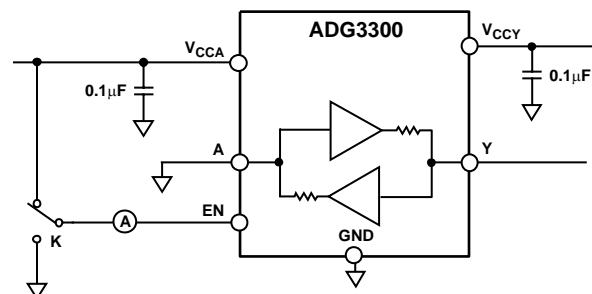


Figure 30. EN Pin Leakage Current

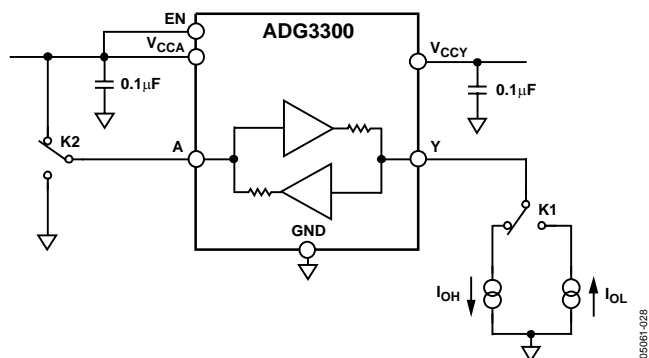


Figure 28. V_{OH}/V_{OL} Voltages at Pin Y

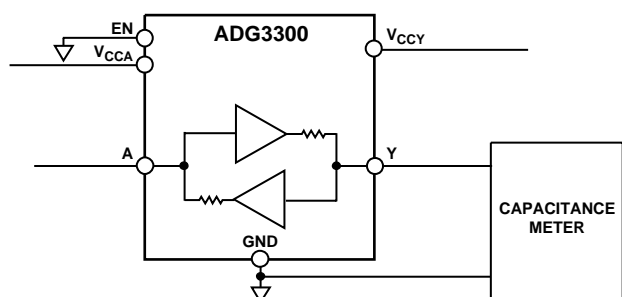


Figure 31. Capacitance at Pin Y

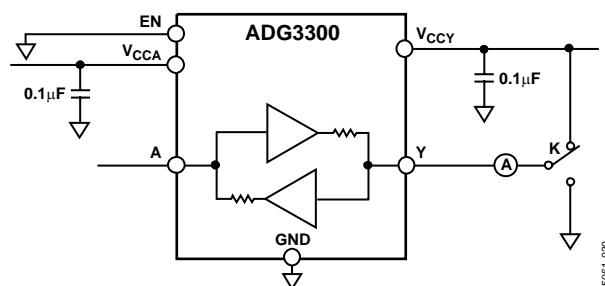
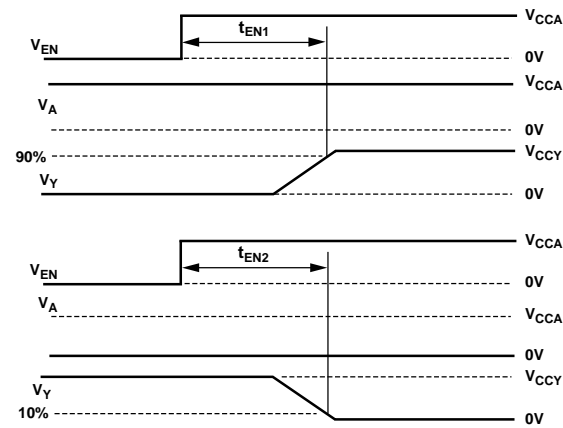
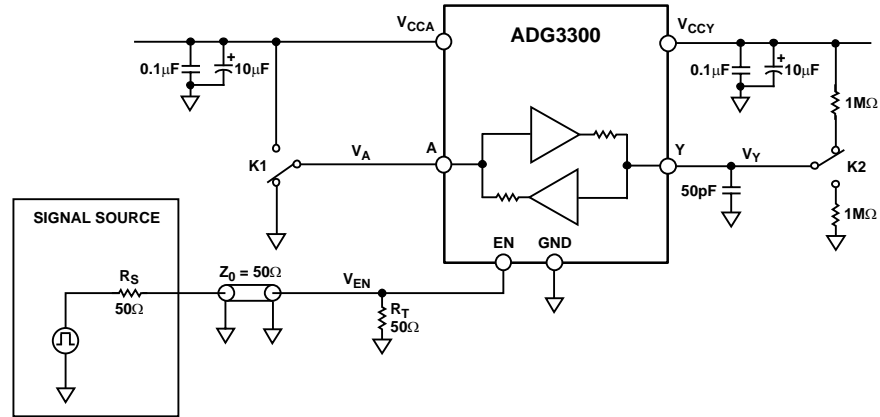


Figure 29. Three-State Leakage Current at Pin Y



NOTES

1. t_{EN} IS WHICHEVER IS LARGER BETWEEN t_{EN1} AND t_{EN2} .

Figure 32. Enable Time

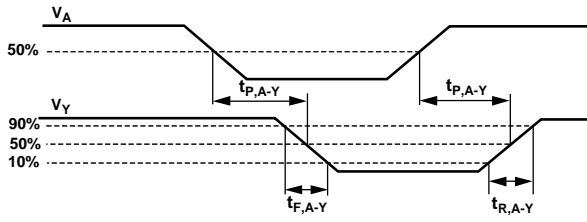
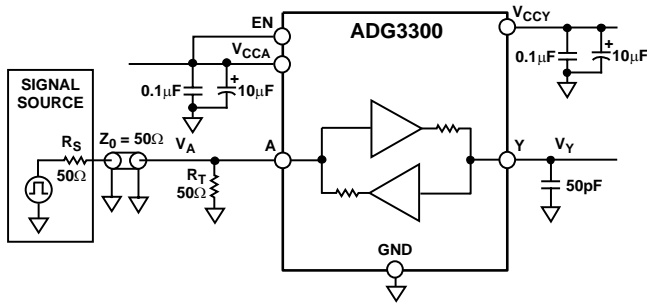


Figure 33. Switching Characteristics (A Y Level Translation)

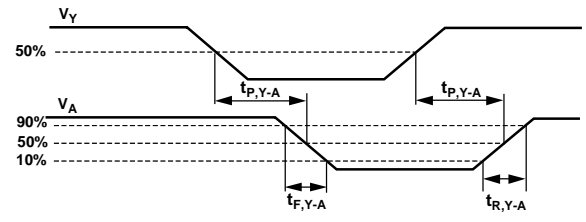
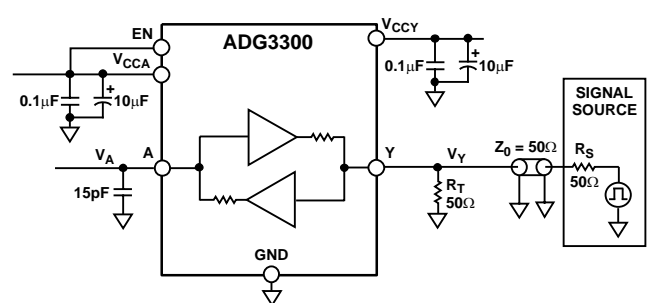


Figure 34. Switching Characteristics (Y A Level Translation)

TERMINOLOGY

Table 4.

Symbol	Description
V_{IHA}	Logic input high voltage at Pins A1 to A8.
V_{ILA}	Logic input low voltage at Pins A1 to A8.
V_{OHA}	Logic output high voltage at Pins A1 to A8.
V_{OLA}	Logic output low voltage at Pins A1 to A8.
$R_{A,HIZ}$	Pull-down resistance measured at Pins A1 to A8 when $EN = 0$.
V_{IHY}	Logic input high voltage at Pins Y1 to Y8.
V_{ILY}	Logic input low voltage at Pins Y1 to Y8.
V_{OHY}	Logic output high voltage at Pins Y1 to Y8.
V_{OLY}	Logic output low voltage at Pins Y1 to Y8.
C_Y	Capacitance measured at Pins Y1 to Y8 ($EN = 0$).
$I_{LY, HIZ}$	Leakage current at Pins Y1 to Y8 when $EN = 0$ (high impedance state at Pins Y1 to Y8).
V_{IHEN}	Logic input high voltage at the EN pin.
V_{ILEN}	Logic input low voltage at the EN pin.
C_{EN}	Capacitance measured at EN pin.
I_{LEN}	Enable (EN) pin leakage current.
t_{EN}	Three-state enable time for Pins Y1 to Y8.
$t_{P, A-Y}$	Propagation delay when translating logic levels in the A Y direction.
$t_{R, A-Y}$	Rise time when translating logic levels in the A Y direction.
$t_{F, A-Y}$	Fall time when translating logic levels in the A Y direction.
$D_{MAX, A-Y}$	Guaranteed data rate when translating logic levels in the A Y direction under the driving and loading conditions specified in Table 1.
$t_{SKEW, A-Y}$	Difference between propagation delays on any two channels when translating logic levels in the A Y direction.
$t_{PPSKEW, A-Y}$	Difference in propagation delay between any one channel and the same channel on a different part (under the same driving/loading conditions) when translating logic levels in the A Y direction.
$t_{P, Y-A}$	Propagation delay when translating logic levels in the Y A direction.
$t_{R, Y-A}$	Rise time when translating logic levels in the Y A direction.
$t_{F, Y-A}$	Fall time when translating logic levels in the Y A direction.
$D_{MAX, Y-A}$	Guaranteed data rate when translating logic levels in the Y A direction under the driving and loading conditions specified in Table 1.
$t_{SKEW, Y-A}$	Difference between propagation delays on any two channels when translating logic levels in the Y A direction.
$t_{PPSKEW, Y-A}$	Difference in propagation delay between any one channel and the same channel on a different part (under the same driving/loading conditions) when translating in the Y A direction.
V_{CCA}	V_{CCA} supply voltage.
V_{CCY}	V_{CCY} supply voltage.
I_{CCA}	V_{CCA} supply current.
I_{CCY}	V_{CCY} supply current.
I_{HIZA}	V_{CCA} supply current during three-state mode ($EN = 0$).
I_{HIZY}	V_{CCY} supply current during three-state mode ($EN = 0$).

ADG3300

DATA RATE

The maximum data rate at which the device is guaranteed to operate is a function of the V_{CCA} and V_{CCY} supply voltage combination and the load capacitance. It is given by the maximum frequency of a square wave that can be applied to the device, which meets the V_{OH} and V_{OL} levels at the output and does not exceed the maximum junction temperature (see Table 2). Table 6 shows the guaranteed data rates at which the ADG3300 can operate in both directions (A Y and Y A level translation) for various V_{CCA} and V_{CCY} supply combinations.

Table 6. Guaranteed Data Rate (Mbps)¹

V_{CCA}	V_{CCY}			
	1.8 V (1.65 V to 1.95 V)	2.5 V (2.3 V to 2.7 V)	3.3 V (3.0 V to 3.6 V)	5 V (4.5 V to 5.5 V)
1.2 V (1.15 V to 1.3 V)	25	30	40	40
1.8 V (1.65 V to 1.95 V)	-	45	50	50
2.5 V (2.3 V to 2.7 V)	-	-	60	50
3.3 V (3.0 V to 3.6 V)	-	-	-	50
5 V (4.5 V to 5.5 V)	-	-	-	-

¹ The load capacitance used is 50 pF when translating in the A Y direction and 15 pF when translating in the Y A direction.

APPLICATIONS

The ADG3300 is designed for digital circuits that operate at different supply voltages; therefore, logic level translation is required. The lower voltage logic signals are connected to the A pins, and the higher voltage logic signals are connected to the Y pins. The ADG3300 can provide level translation in both directions from A to Y and Y to A on all eight channels, eliminating the need for a level translator IC for each direction. The internal architecture allows the ADG3300 to perform bidirectional level translation without an additional signal to set the direction of the translation. It also allows simultaneous data flow in both directions on the same part, for example, four channels translate in the A to Y direction while the other four translate in the Y to A direction. This simplifies the design by eliminating the timing requirements for the direction signal and reduces the number of ICs used for level translation.

Figure 36 shows an application where a 1.8 V microprocessor can read or write data to or from a 3.3 V peripheral device using an 8-bit bus.

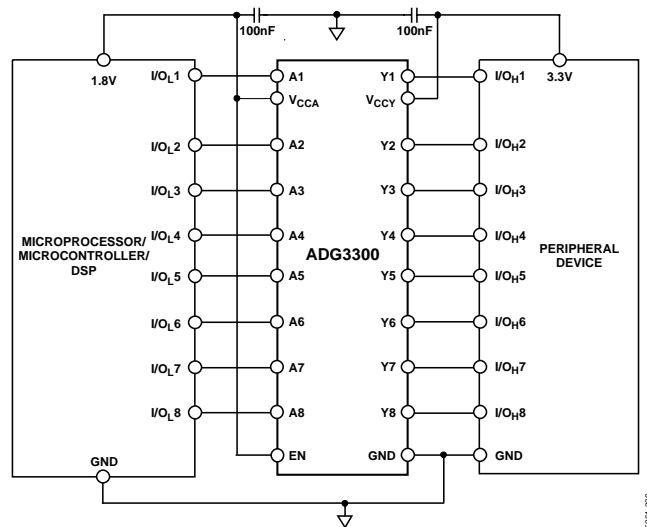


Figure 36. 1.8 V to 3.3 V 8-Bit Level Translation Circuit

When the application requires level translation between a microprocessor and multiple peripheral devices, the ADG3300 Y I/O pins (Y1 to Y8) can be three-stated by setting EN = 0. This feature allows the ADG3300 to share the data buses with

other devices without causing contention issues. Figure 37 shows an application where a 3.3 V microprocessor is connected to 1.8 V peripheral devices using the three-state feature.

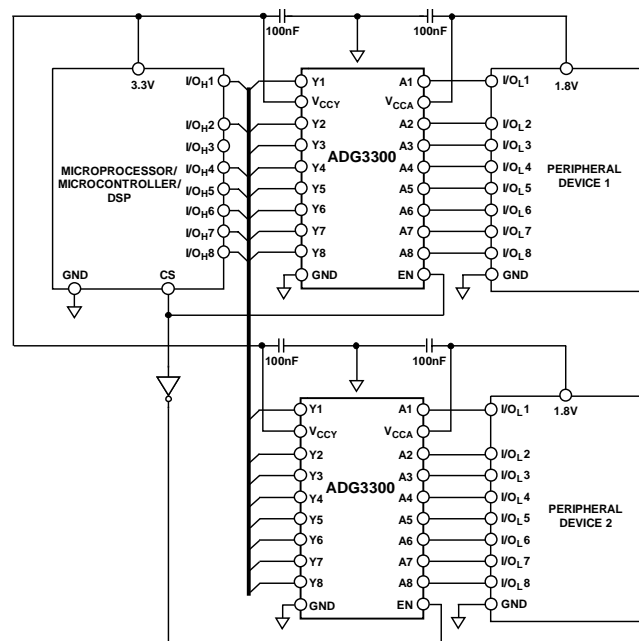


Figure 37. 1.8 V to 3.3 V Level Translation Circuit Using the Three-State Feature

LAYOUT GUIDELINES

As with any high speed digital IC, the printed circuit board layout is important in the overall circuit performance. Care should be taken to ensure proper power supply bypass and return paths for the high speed signals. Each V_{CC} pin (V_{CCA} and V_{CCY}) should be bypassed using low effective series resistance (ESR) and effective series inductance (ESI) capacitors placed as close as possible to the V_{CCA} and V_{CCY} pins. The parasitic inductance of the high speed signal track might cause significant overshoot. This effect can be reduced by keeping the length of the tracks as short as possible. A solid copper plane for the return path (GND) is also recommended.

OUTLINE DIMENSIONS

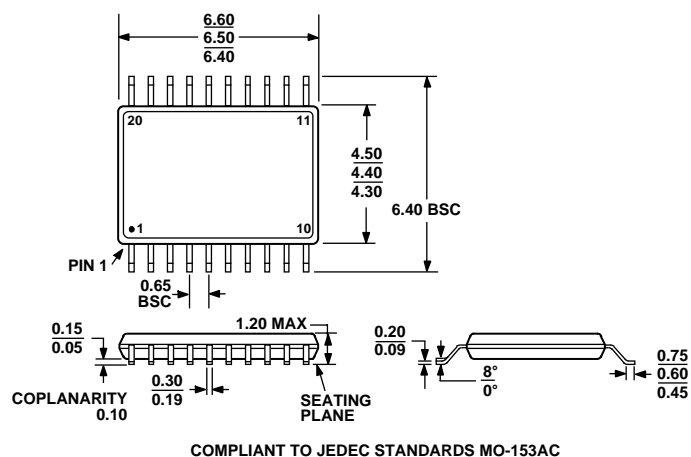


Figure 38 . 20-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-20)
Dimensions shown in millimeters

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADG3300BRUZ ¹	−40°C to +85°C	TSSOP	RU-20
ADG3300BRUZ-REEL ¹	−40°C to +85°C	TSSOP	RU-20
ADG3300BRUZ-REEL7 ¹	−40°C to +85°C	TSSOP	RU-20

¹ Z = Pb-free part.

NOTES

ADG3300

NOTES

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[ADG3300BRUZ](#) [ADG3300BRUZ-REEL7](#)